

## Structure and Properties of dmit Systems

	構造	伝導度	その他
Ni(dmit) <sub>2</sub>	P2 <sub>1</sub> /a (#43)		
TTF[Ni(dmit) <sub>2</sub> ] <sub>2</sub>	C2/c (#30) バンド構造 (#34 および R1)	$\rho_{tt}$ =300 (#30) $T_c$ =1.6K (7kbar) (R3,#33 等) 常圧下では金属	(#4), NMR(#28) 温度 - 圧力相図(#33) 物性一般 ( R3 の文献を見よ )
-EDT-TTF[Ni(dmit) <sub>2</sub> ]	P1-(#7, #22) 交差型	$\rho_{tt}$ =100(//ab) (#7) $\rho_{tt}$ =140~370(//ab); $\rho_{tt}$ =14~36(//c*) (#14) $T_{M-M}$ =14 K(#7) $T_{SC}$ =1.3K(#8)	Magnetoresistance(#9) $H_{c2}$ (#10) Opt. (#11) Meissner (#12 ) (#13) ESR (#22)
-EDT-TTF[Ni(dmit) <sub>2</sub> ]	mixed stack P2 <sub>1</sub> /c (#7)	$\rho_{tt}$ =0.01; semicon.	
-EDT-TTF[Ni(dmit) <sub>2</sub> ]	1D (#22)	$\rho_{tt}$ =100; $T_{M-I}$ =100 K	
TMTSF[Ni(dmit) <sub>2</sub> ]	1D (TMTSF) (#19)	$\rho_{tt}$ =300 ;semicon. $E_a$ =0.034eV (#19)	
-(BPDT-TTF) [Ni(dmit) <sub>2</sub> ] <sub>2</sub>	1D (#20)	$\rho_{tt}$ =5~10; $E_a$ = 0.012eV (r.t.~120K) ; $T_{S-S}$ =120 K (#20)	
(DBTTF)[Ni(dmit) <sub>2</sub> ]	2-chain (#23)	$\rho_{tt}$ =100	
(ET)[Ni(dmit) <sub>2</sub> ]	mixed stack (#24)	$\rho_{tt}$ =10 <sup>-3</sup> ; $E_a$ =0.28eV	
OMTSF[Ni(dmit) <sub>2</sub> ] (#50)	mixed stack (#50)	$\rho_{tt}$ =10(#50)	Opt(#50)
[Pt(dddt) <sub>2</sub> ][Ni(dmit) <sub>2</sub> ]	monoclinic (#53)	insulator	
(NH <sub>2</sub> Me <sub>2</sub> )[Ni(dmit) <sub>2</sub> ] <sub>2</sub>	P1-(#6,#48)	$\rho_{tt}$ =0.08(//ab) (#6) semicon. $E_a$ =0.2eV	
(NHMe <sub>3</sub> )[Ni(dmit) <sub>2</sub> ] <sub>2</sub>	P1-(#48)	$\rho_{tt}$ =140; semicon.	
(NHMe <sub>3</sub> ) <sub>2</sub> [Ni(dmit) <sub>2</sub> ] <sub>5</sub> . 2CH <sub>3</sub> CN	P1-(#48)	$\rho_{tt}$ =0.2(//ab) (#6) semicon. $E_a$ =0.2eV	
(NH <sub>3</sub> Me) <sub>2</sub> [Ni(dmit) <sub>2</sub> ] <sub>5</sub> . 2CH <sub>3</sub> CN	P1-(#48)	$\rho_{tt}$ =1.5(//ab) (#6) semicon. $E_a$ =0.2eV	
-Et <sub>2</sub> Me <sub>2</sub> N[Ni(dmit) <sub>2</sub> ] <sub>2</sub>	C2/c(R.T.:#16) P2 <sub>1</sub> /c(17K:#27) 2DFS(#27)	$\rho_{tt}$ =20~100(//bc) (#16); $\rho_{tt}$ =2.5(//a*) (#17) $T_{M-M}$ =245 K (#17)	SdH (#17,#18) AMRO (#17) (#54)

$-\text{Et}_2\text{Me}_2\text{N}[\text{Ni}(\text{dmit})_2]_2$	Pnma (RT); P2 <sub>1</sub> 2 <sub>1</sub> 2 <sub>1</sub> (4.3K) ; (#54)	metallic metal-metal transition をし めさない (#54)	(#54)
$(\text{C}_7\text{H}_{16}\text{N})[\text{Ni}(\text{dmit})_2]_2$	C2/c (300K) Cc(20K) (#51)	metallic down to 0.5K (#51) $T_{\text{M-M}}=225\text{K}$	(#54)
$(\text{Et}_4\text{N})_{0.5}[\text{Ni}(\text{dmit})_2]$	(#25)	$\rho_{\text{rt}}(\parallel b) = 4.5 \times 10^{-2}$ ; semicon. (#25)	
$(\text{CH}_3)_4\text{N}[\text{Ni}(\text{dmit})_2]_2$	C2/c (#39) X-ray 温度依存性 (#39) FS (#39a,c, #32)	$\rho_{\text{rt}} = 50$ (#32); $T_{\text{M-I}} = 40\text{K}$ , $T_{\text{I}}$ $\rho_{\text{I}} = 20\text{K}$ (#41); $T_{\text{sc}} = 5\text{K}$ (7kbar;#39)	(#41), S(#41), Opt.(#42a)
$[\text{Bu}_4\text{N}]_2[\text{Ni}(\text{dmit})_2]_7 \cdot 2\text{CH}_3\text{CN}$	P1- (#43)	$\rho_{\text{rt}} = 1-10$ ; semicon.; $E_{\text{a}} = 0.1 \sim 0.02\text{eV}$ (#43)	Opt.(#52)
$(\text{Ph}_4\text{As})_{0.25}[\text{Ni}(\text{dmit})_2]$	P2/n(#45)	$\rho_{\text{rt}} = 10-15$ ; semicon.; $E_{\text{a}} = 0.03 \sim 0.01\text{eV}$ (#45)	
$\text{Ph}_4\text{P}[\text{Ni}(\text{dmit})_2]_3$	C2/c (#52)	$\rho_{\text{rt}} = 10$ ; $E_{\text{a}} \sim 46\text{meV}$ semicon. (#36) $\rho_{\text{rt}} = 7$ ; semicon; $E_{\text{a}} =$ $0.01\text{eV}$ (#52)	, opt, S (#36) Opt.(#52)
$\text{Me}(\text{Ph})_3\text{P}[\text{Ni}(\text{dmit})_2]_3$	P2 <sub>1</sub> /c (#56)	$0.07 \sim 0.1$ ; $E_{\text{a}} = 0.22\text{eV}$ (#56)	
$(\text{Me}_3\text{S})[\text{Ni}(\text{dmit})_2]_2$	P1- (#52)	$\rho_{\text{rt}} = 6.5 \times 10^{-2}$ ; semicon.; $E_{\text{a}} = 0.13\text{eV}$ (#52)	Opt.(#52)
$\text{AcrH}[\text{Ni}(\text{dmit})_2]_3$	C2/c (#75, #76)	$\rho_{\text{rt}} = 45$ metallic down to 4K	
$\text{MEA}[\text{Ni}(\text{dmit})_2]_3 \cdot \text{MeCN}$	P2 <sub>1</sub> /c (#74)		
$\text{Hmorph}_2[\text{Ni}(\text{dmit})_2]_3$	P2 <sub>1</sub> /n (#74)	$\rho_{\text{rt}} = 0.1$ ; semicon.; $E_{\text{a}} = 0.1\text{eV}$	
$\text{HMemorph}[\text{Ni}(\text{dmit})_2]_2$	P1- (#74)	$\rho_{\text{rt}} = 4$ ; semicon.; $E_{\text{a}} = 0.1\text{eV}$	
[guanidinium] $[\text{Ni}(\text{dmit})_2]_2$	P1- (#63)	$\rho_{\text{rt}} = 32$ ; semicon.; $E_{\text{a}} = 0.12\text{eV}$ (#63)	
[1,1-dimethylguanidinium] $[\text{Ni}(\text{dmit})_2]_2$	P1- (#63)	$\rho_{\text{rt}} = 0.15$ ; semicon.; $E_{\text{a}} = 0.13\text{eV}$ (#63)	
$[\text{Me}_3\text{N}(\text{CH}_2)_4\text{NMe}_3][\text{Ni}(\text{dmit})_2]_5 \cdot 2\text{dmf}$	P1-(#64)	$\rho_{\text{rt}} = 1$ ; semicon.; $E_{\text{a}} = 0.0.19\text{eV}$ (#64)	
$[\text{Me}_3\text{N}(\text{CH}_2)_4\text{NMe}_3][\text{Ni}(\text{dmit})_2]_5 \cdot 2\text{CH}_3\text{CN}$	P1(#64)	$\rho_{\text{rt}} = 0.1$ ; semicon.; $E_{\text{a}} = 0.20\text{eV}$ (#64)	
$[\text{Li}]_2[12\text{-crown-4}]_3 \cdot [\text{Ni}(\text{dmit})_2]_7 \cdot [\text{acetone}]_2$	P1-(#58,#59)	$\rho_{\text{rt}} = 30$ ; semicon.; $E_{\text{a}} = 0.1$ $\text{eV}$ ( $T > 230\text{K}$ ), $E_{\text{a}} = 0.17\text{eV}$ ( $T < 230\text{K}$ ) (#58,#59)	

[NH <sub>4</sub> ][15-crown-5] <sub>2</sub> . [Ni(dmit) <sub>2</sub> ]	C2/c(#58)	$\rho_{rt} = 10^{-6}$ ; insulator (#58)	
[NH <sub>4</sub> ][18-crown-6]. [Ni(dmit) <sub>2</sub> ] <sub>3</sub>	P1-(#58)	$\rho_{rt} = 0.4$ ; semicon.; $E_a = 0.15$ ( $T > 230K$ ), $E_a = 0.07eV$ ( $T < 230K$ ) (#58)	
Li <sub>0.6</sub> (15-crown-5- ether)[Ni(dmit) <sub>2</sub> ] <sub>2</sub> .H <sub>2</sub> O	P2 <sub>1</sub> /c (#60)	$\rho_{rt} = 240$ ; $T_{M-I} = 250 K$ (#60)	, NMR(#60)
Li[Ni(dmit) <sub>2</sub> ] <sub>2</sub> .2CH <sub>3</sub> CN (1); Na[Ni(dmit) <sub>2</sub> ] <sub>2</sub> (2); K <sub>0.4</sub> [Ni(dmit) <sub>2</sub> ] (3); Rb <sub>0.36</sub> [Ni(dmit) <sub>2</sub> ] (4); Cs[Ni(dmit) <sub>2</sub> ] <sub>2</sub> (5)		(1) $\rho_{rt} = 0.5$ ; semicon. (2) $\rho_{rt} = 20$ ; metal (3) $\rho_{rt} = 100$ ; metal (4) $\rho_{rt} = 10$ ; semicon. (R3)	
p-EYPNN[Ni(dmit) <sub>2</sub> ]	P1- spin-ladder(#38)	$\rho_{rt} = 1.3 \times 10^{-4}$ (#38); Semicon.	(#38)
C <sub>1</sub> <sup>+</sup> [Ni(dmit) <sub>2</sub> ] <sup>-</sup> (1) C <sub>1</sub> <sup>+</sup> [Ni(dmit) <sub>2</sub> ] <sup>-</sup> (2) C <sub>2</sub> <sup>+</sup> [Ni(dmit) <sub>2</sub> ] <sup>-</sup> (3) C <sub>2</sub> <sup>+</sup> [Ni(dmit) <sub>2</sub> ] <sup>-</sup> (4) C <sub>1</sub> , C <sub>2</sub> = Cyanine Dyes	(1),(3) P2 <sub>1</sub> /c (2),(4) P1- (#55)	$\rho_{rt}[(2) \sim (3)] = 10^{-6} \sim 10^{-5}$ (powder) $\rho_{rt}[(1)] = 1.3 \times 10^{-2}$ $E_a = 0.05eV$ (#55)	
( , ')-TTF[Pd(dmit) <sub>2</sub> ] <sub>2</sub> (二つの相が同じ物か別 かが不明 )	C2/c (#29;R3) TTF[Ni(dmit) <sub>2</sub> ] <sub>2</sub> と 同型構造 E(k) (#34: ')	$\rho_{rt} = 750$ ( , '共:R3) $T_{M-I} = 220K$ (1 bar) $T_{sc} = 5.9K$ (24kbar: ') $T_{sc} = 1.2K$ (19.25kbar: ') (#35)	(#4: ', の区別なし)
-TTF[Pd(dmit) <sub>2</sub> ] <sub>2</sub>	P1-(#29)		
-TTF[Pd(dmit) <sub>2</sub> ] <sub>2</sub>	P1-(#29)		
-TTF[Pd(dmit) <sub>2</sub> ] <sub>2</sub>	P1-(#29)	100 $T_{M-I} = 100$ (#29)	
'-EDT-TTF[Pd(dmit) <sub>2</sub> ]	P1- (#47) Fermi 面(#47, #31)	$\rho_{rt} = 58$ $T_{M-M} = 40K$ metal (#31)	X-Ray; (#47)
EDT-TTF <sub>2</sub> [Pd(dmit) <sub>2</sub> ] <sub>3</sub>	P1-; E(k) (#47)	$\rho_{rt} = 120$ ; (#47) 温度依存性 のデータなし	
-EDT-TTF[Pd(dmit) <sub>2</sub> ]	diffuse, 温度依存 性を含む(#22)	$\rho_{rt}(/: 2.4kbar) \sim 150$ ; $T_{M-}$ $T_M = 80K$ (#22); metallic down to 2K (2.4kbar) (#22)	
IEDT[Pd(dmit) <sub>2</sub> ]	P1-(#67)	$\rho_{rt} = 300$ ; metallic down to 4.2K (#67)	

$\text{Cs}[\text{Pd}(\text{dmit})_2]_2$	C2/c (#15;#34)	$\eta = 100$ (//ab) (#15)	, ,Opt.(#15;#42)
$\text{Et}_2\text{Me}_2\text{N}[\text{Pd}(\text{dmit})_2]_2$	P1- open FS (#57)	$\eta = 10\sim 80$ ; $T_{\text{sc}} = 4\text{K}$ (2.4kbar) (#57)	
$-(\text{CH}_3)_4\text{N}[\text{Pd}(\text{dmit})_2]_2$	P1- (#26)	$\eta = 50$ ; semicon.(1bar)	
$-(\text{CH}_3)_4\text{N}[\text{Pd}(\text{dmit})_2]_2$	C2/c(#26) ;FS (#70,#71, #72)	$\eta = 30$ ; semicon.(1bar) $T_{\text{sc}}=6.2\text{K}$ (6.5 kbar) (#70 )	
$-(\text{CH}_3)_4\text{As}[\text{Pd}(\text{dmit})_2]_2$	C2/c (#26); FS(#71, #72)	$\eta = 1$ ; semicon.; $E_a = 0.07$ eV; 高圧下で 4.2K まで金属的(#72)	Opt. (#42)
$-(\text{CH}_3)_4\text{P}[\text{Pd}(\text{dmit})_2]_2$	C2/c (#37); FS (#71, #72)	$\eta = 20$ ; $T_{\text{M-I}}=60\text{K}$ ; $\eta = 1$ ; semicon.; $E_a=0.07\text{eV}$ (#37); 高圧下で 4.2K まで金属的 (#72)	(#72)
$-(\text{CH}_3)_4\text{Sb}[\text{Pd}(\text{dmit})_2]_2$	C2/c ;FS (#71, #72)	$\eta = 20$ ; semicon.; 高圧下 で 4.2K まで金属的 (#71, #72)	
$(\text{Et}_4\text{N})_{0.5}[\text{Pd}(\text{dmit})_2]$	(#62,R3)	$\eta = 0.11$ ; semicon.(R3)	
$n\text{-Bu}_4\text{N}_{0.5}[\text{Pd}(\text{dmit})_2]$	P1-(#61)	$\eta = 12$ ; $T_{\text{M-I}}=240\text{K}$ (#61)	
$(n\text{-Bu}_4\text{N})_{0.33}[\text{Pd}(\text{dmit})_2]$	P1-(#61)	$\eta = 150$ ; $T_{\text{M-I}}=120\text{K}$ (initial); semicon. (after heat cycle) (#61)	
${}^-\text{Et}_2\text{Me}_2\text{P}[\text{Pd}(\text{dmit})_2]_2$	C2/c (#69)	$\eta = 10$ ; semicon.; $T_{\text{sc}}=4\text{K}$ at 6.9 kbar (#68)	特異な相図
${}^-\text{Et}_2\text{Me}_2\text{Sb}[\text{Pd}(\text{dmit})_2]_2$	C2/c (#69)	$\eta = 1$ ; semicon.; 高圧下で金属的 (#68)	
$\text{TTF}[\text{Pt}(\text{dmit})_2]_3$	P1-(#30)	$\eta = 20$ ; $E_a=0.03\text{eV}$ (300–200K: #30)	
$(\text{HMTTeF})_2[\text{Pt}(\text{dmit})_2]$	2D (#21)	$\eta = 5\sim 10$ ; semicon.;	
$\text{CH}_3\text{N}[\text{Pt}(\text{dmit})_2]_2$	C2/c(#1) Band Structure (#1)	$\eta = 10$ (//ab) (#1) $T_{\text{MI}} = 220\text{K}$	Opt. (#2)
$(\text{NHMe}_3)[\text{Pt}(\text{dmit})_2]_3$ , $\text{CH}_3\text{CN}$	P1-(#5,#48)	$\eta = 140$ (//ab) (#5; #6) $T_{\text{MI}} = 180\text{K}$	

Me <sub>4</sub> N[Au(dmit) <sub>2</sub> ] <sub>2</sub>	B2/b(#3)	$\rho_{rt} = 5-15(//a)$ (#3) Semicon.	
Et <sub>4</sub> N[Au(dmit) <sub>2</sub> TCNQ]	P1-(#49)	$\rho_{rt} = 1 \times 10^{-5}$ (#49)	opt. (#49)
(ET) <sub>3</sub> [V(dmit) <sub>3</sub> ] <sub>2</sub>	P1-(#46a) E(k) (#46b)	$\rho_{rt} = 3-45$ ; semicon. ;E <sub>a</sub> =0.020eV T<150 K	
[NBu <sub>4</sub> ] <sub>2</sub> [W(dmit) <sub>3</sub> ]	Pca2 <sub>1</sub> (#44)	insulator	
[NBu <sub>4</sub> ] <sub>2</sub> [Mo(dmit) <sub>3</sub> ]	Pca2 <sub>1</sub> (#44)	insulator	
[Fe(C <sub>5</sub> Me <sub>5</sub> ) <sub>2</sub> ][W(dmit) <sub>3</sub> ]	P1-(#44)	insulator	
-[Me <sub>4</sub> N][Ni(dmise) <sub>2</sub> ] <sub>2</sub>	Pbnb (#65)	$\rho_{rt} = 1$ ; semicon.; E <sub>a</sub> =0.08eV (#65)	
-[Me <sub>4</sub> N][Ni(dmise) <sub>2</sub> ] <sub>2</sub>	C2/c (#65)	$\rho_{rt} = 10$ ; semicon.; E <sub>a</sub> =0.05eV (#65)	
D [Pd(dmise) <sub>2</sub> ] <sub>2</sub> (1): D=(CH <sub>3</sub> ) <sub>4</sub> N; (2): D=(CH <sub>3</sub> ) <sub>4</sub> P; (3): D=(CH <sub>3</sub> ) <sub>4</sub> As; (4): D=(CH <sub>3</sub> ) <sub>4</sub> Sb;	C2/c; E(k) (#66, #72)	$\rho_{rt} = 200 \sim 20$ ; T <sub>M-I</sub> =150 K (#66); 圧力依存性を含めた詳細なデータ(#72)	(2): (#72); NMR(#73)
NMe <sub>4</sub> [Pd(dsit) <sub>2</sub> ] <sub>2</sub>	C2/c (#37)	$\rho_{rt} = 30-70$ (#37) T <sub>M-I</sub> =220K	Opt (#37)

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